

RJH60F7DPQ-A0

Silicon N Channel IGBT
High Speed Power Switching

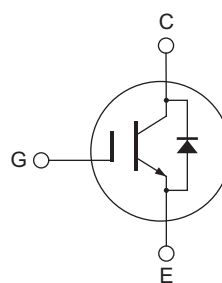
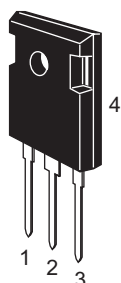
R07DS0328EJ0100
Rev.1.00
Apr 06, 2011

Features

- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.35 \text{ V typ. (at } I_C = 50 \text{ A, } V_{GE} = 15 \text{ V, } T_a = 25^\circ\text{C)}$
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 74 \text{ ns typ. (at } I_C = 30 \text{ A, } V_{CE} = 400 \text{ V, } V_{GE} = 15 \text{ V, } R_g = 5 \Omega, T_a = 25^\circ\text{C, inductive load)}$

Outline

RENESAS Package code: PRSS0003ZH-A
(Package name: TO-247A)



1. Gate
2. Collector
3. Emitter
4. Collector

Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V_{CES}	600	V
Gate to emitter voltage		V_{GES}	± 30	V
Collector current	$T_c = 25^\circ\text{C}$	I_C	90	A
	$T_c = 100^\circ\text{C}$	I_C	50	A
Collector peak current		$i_{c(peak)}$ ^{Note1}	180	A
Collector to emitter diode forward peak current		$i_{DF(peak)}$ ^{Note2}	100	A
Collector dissipation		P_C	328.9	W
Junction to case thermal impedance (IGBT)		θ_{j-c}	0.38	$^\circ\text{C/W}$
Junction to case thermal impedance (Diode)		θ_{j-cd}	2.0	$^\circ\text{C/W}$
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. Pulse width limited by safe operating area.

2. $PW \leq 5 \mu\text{s}$, duty cycle $\leq 1\%$

Electrical Characteristics

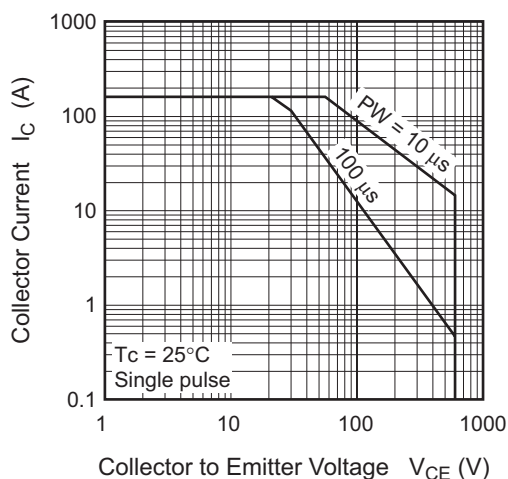
(T_j = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	—	—	100	μA	V _{CE} = 600V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	—	—	±1	μA	V _{GE} = ±30 V, V _{CE} = 0
Gate to emitter cutoff voltage	V _{GE(off)}	4	—	8	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	1.35	1.75	V	I _C = 50 A, V _{GE} = 15V ^{Note3}
	V _{CE(sat)}	—	1.6	—	V	I _C = 90 A, V _{GE} = 15V ^{Note3}
Input capacitance	C _{ies}	—	4700	—	pF	V _{CE} = 25 V
Output capacitance	C _{oes}	—	198	—	pF	V _{GE} = 0 V
Reverse transfer capacitance	C _{res}	—	83	—	pF	f = 1 MHz
Switching time	t _{d(on)}	—	63	—	ns	I _C = 30 A, V _{CE} = 400 V, V _{GE} = 15 V R _g = 5 Ω ^{Note3} Inductive load
	t _r	—	81	—	ns	
	t _{d(off)}	—	142	—	ns	
	t _f	—	74	—	ns	
C-E diode forward voltage	V _{ECF1}	—	1.2	2.1	V	I _F = 20 A ^{Note3}
	V _{ECF2}	—	1.5	—	V	I _F = 40 A ^{Note3}
C-E diode reverse recovery time	t _{rr}	—	90	—	ns	I _F = 20 A di _F /dt = 100 A/μs

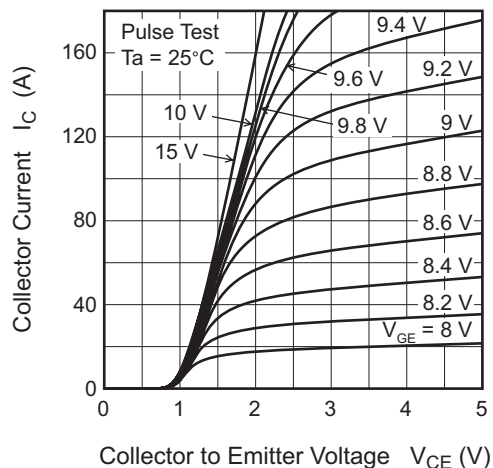
Notes: 3. Pulse test

Main Characteristics

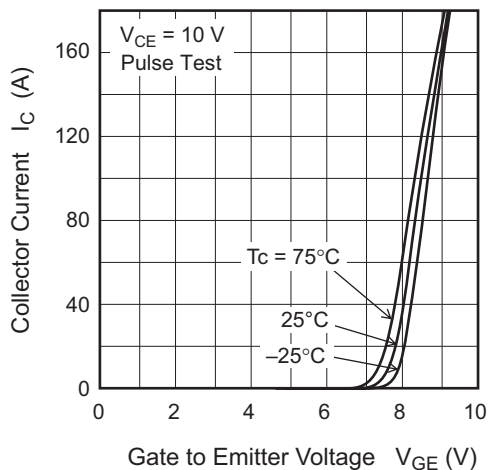
Maximum Safe Operation Area



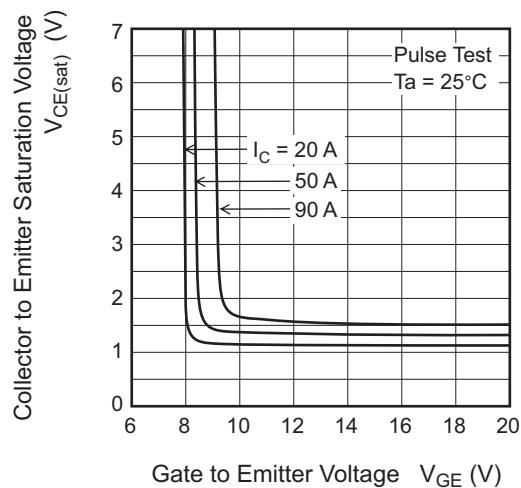
Typical Output Characteristics



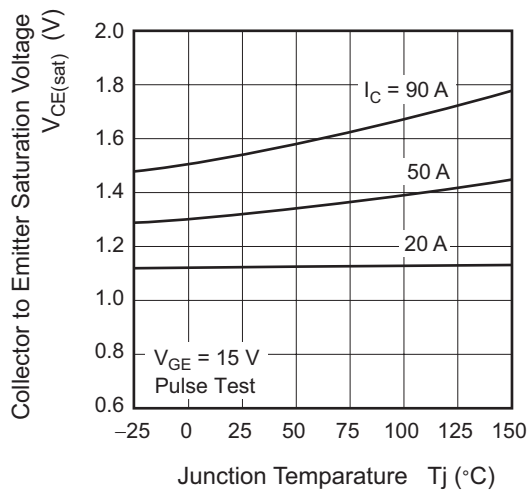
Typical Transfer Characteristics



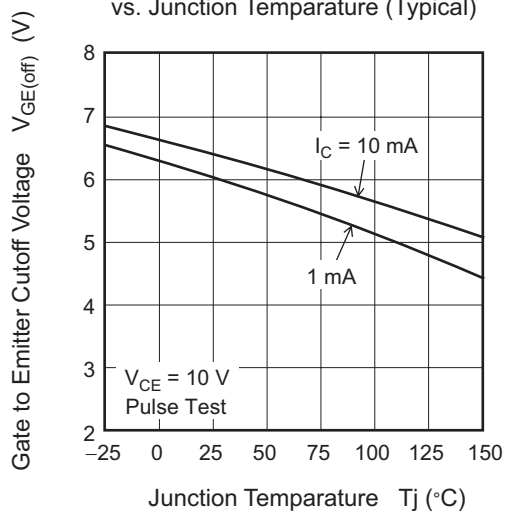
Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage (Typical)



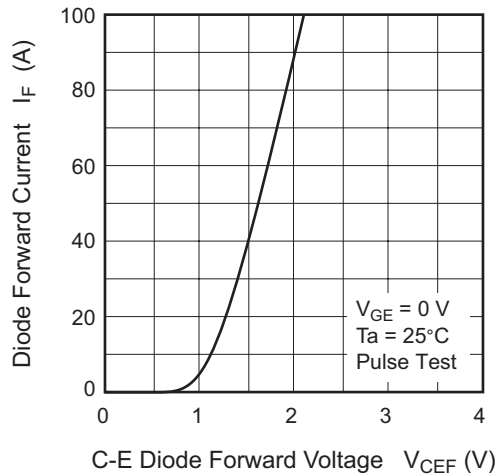
Collector to Emitter Saturation Voltage vs. Junction Temperature (Typical)



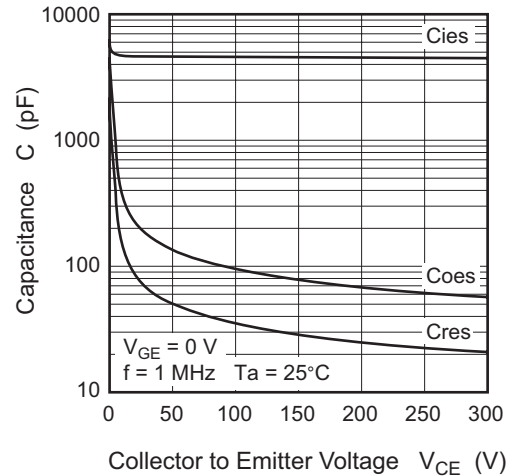
Gate to Emitter Cutoff Voltage vs. Junction Temperature (Typical)



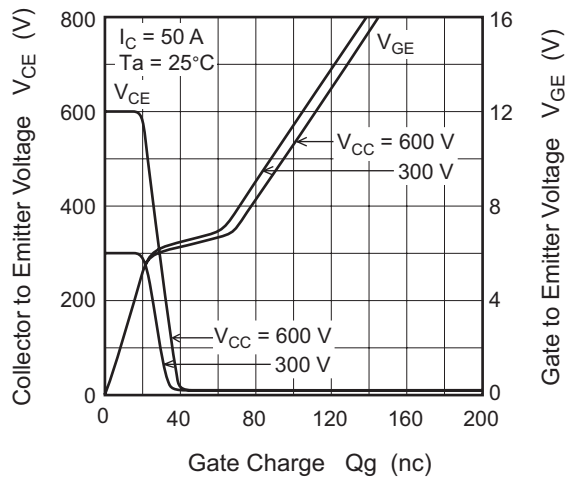
Forward Current vs. Forward Voltage (Typical)



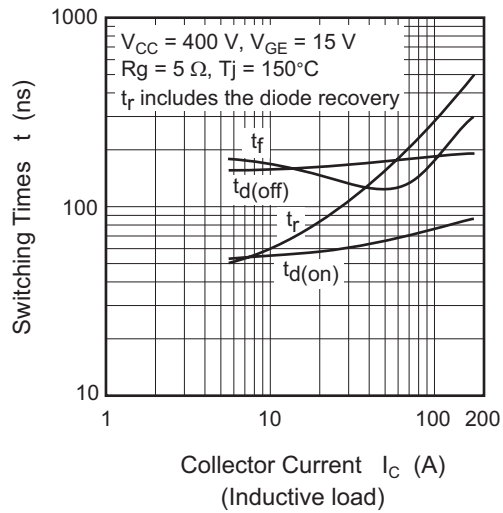
Typical Capacitance vs. Collector to Emitter Voltage



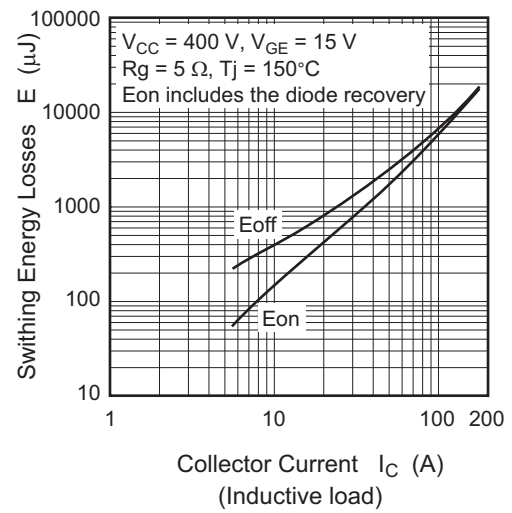
Dynamic Input Characteristics (Typical)



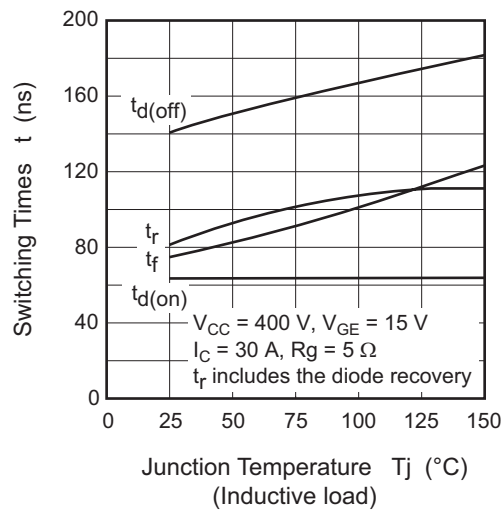
Switching Characteristics (Typical) (1)



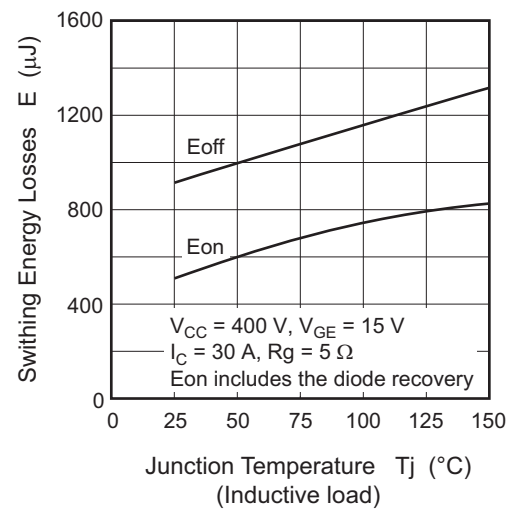
Switching Characteristics (Typical) (2)

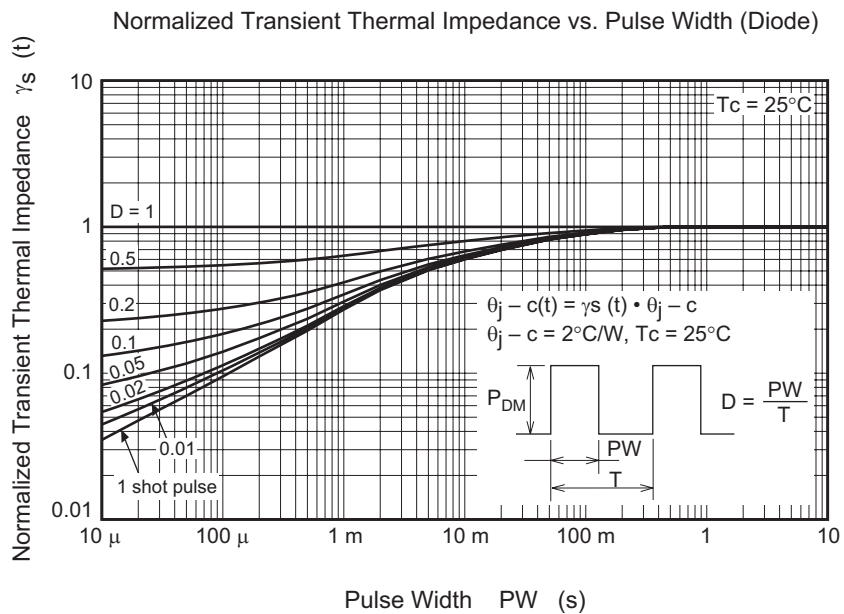
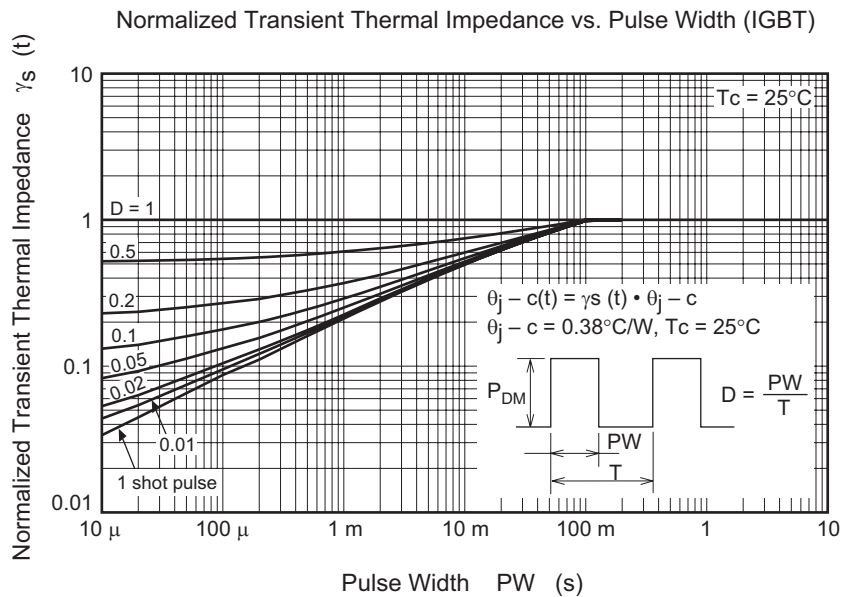


Switching Characteristics (Typical) (3)

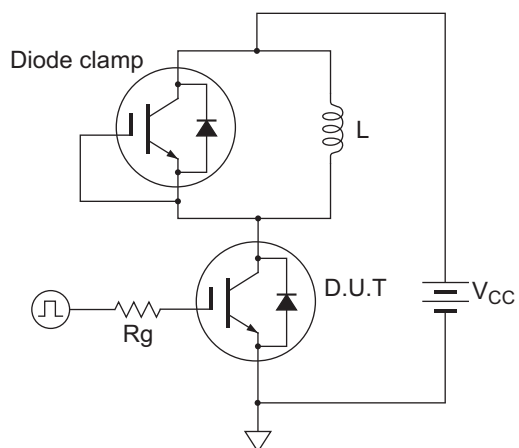


Switching Characteristics (Typical) (4)

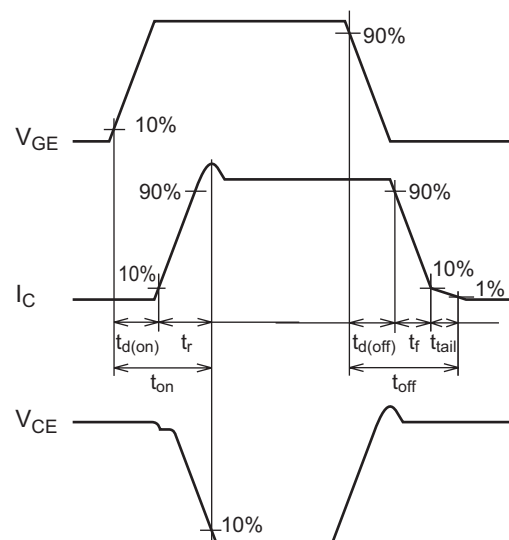




Switching Time Test Circuit



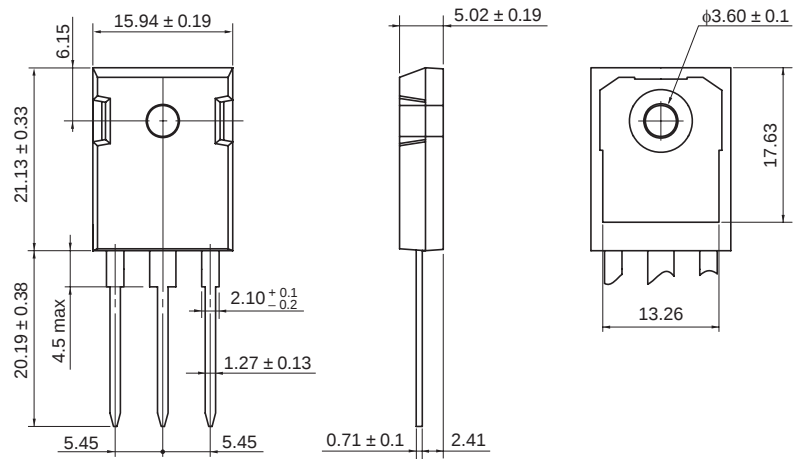
Waveform



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-247A	—	PRSS0003ZH-A	—	6.14g

Unit: mm



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F7DPQ-A0-T0	240 pcs	Box (Tube)

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